Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
Between 670.0 millimeters and 710.0 millimeters	
Terminal Length:	
Between 200.0 millimeters and 225.0 millimeters	
Overall Height:	
Between 40.0 millimeters and 60.0 millimeters	
Overall Width:	
Between 175.0 millimeters and 225.0 millimeters	
Mounting Method:	
Terminal	
Features Provided:	
Gold plated leads	
Criticality Code Justification:	
Feat	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
50.0 breakdown voltage, dc	
Current Rating Per Characteristic:	
10.00 milliamperes all primaries preset	
Power Rating Per Characteristic:	
250.0 milliwatts any acceptable absolute	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Special Features:	
Hardness critical process; junction pattern arrangement: pn	
Precious Material And Location:	
Terminals gold	
Precious Material:	
Gold	
Terminal Type And Quantity:	
2 ribbon	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A110a0	